

MUR560AX ULTRAFAST PLASTIC RECTIFIER

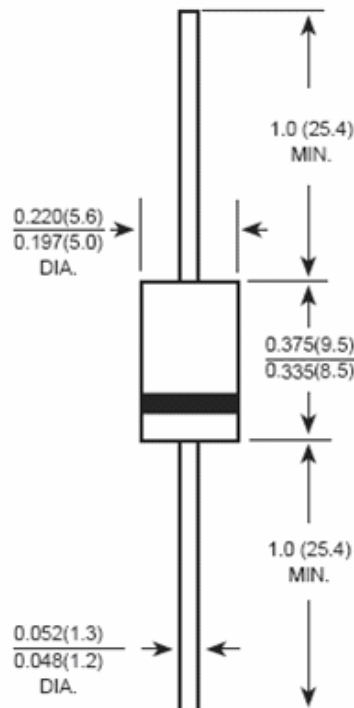
Applications:

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Features:

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Super Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

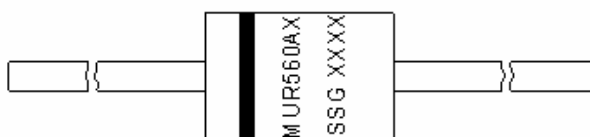
Mechanical Dimensions: In Inches / mm



DO-201AD

Marking Diagram:

Where XXXXX is YYWWL



MUR = Device Type
5 = Forward Current (5A)
60 = Reverse Voltage (600V)
AX = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MUR560AX	DO-201AD (Pb-Free)	1250pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



Maximum Ratings and Electrical Characteristics @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	MUR560AX	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	420	V
Average Rectified Output Current (Note 1) @ $T_A = 55^{\circ}\text{C}$	I_o	5.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150	A
Forward Voltage (per element) @ $I_F = 5.0\text{A}$	V_{FM}	1.7	V
Peak Reverse Current @ $T_A = 25^{\circ}\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^{\circ}\text{C}$	I_{RM}	5.0 500	μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	50	ns
Typical Junction Capacitance (Note 2)	C_j	80	pF
Max. Voltage Rate of Change	dv/dt	10,000	V/ μs
Typical Thermal Resistance Junction to Ambient (Note 3)	$R_{\theta JA}$	25	K/W
Max. Junction Temperature	T_J	-65 to +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^{\circ}\text{C}$
Approximate Weight	wt	1.02	g
Case Style	DO-201AD		

- Note: 1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $IRR=0.25\text{A}$
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
 3. Mount on Cu-Pad Size 16mm×16mm on P.C.B.

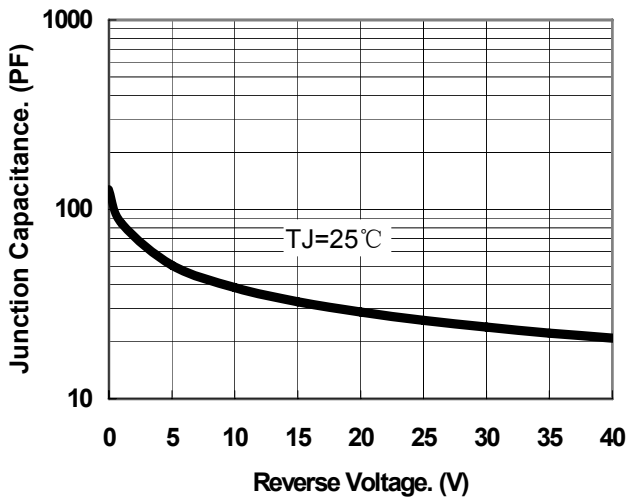


Fig.1-Typical Junction Capacitance

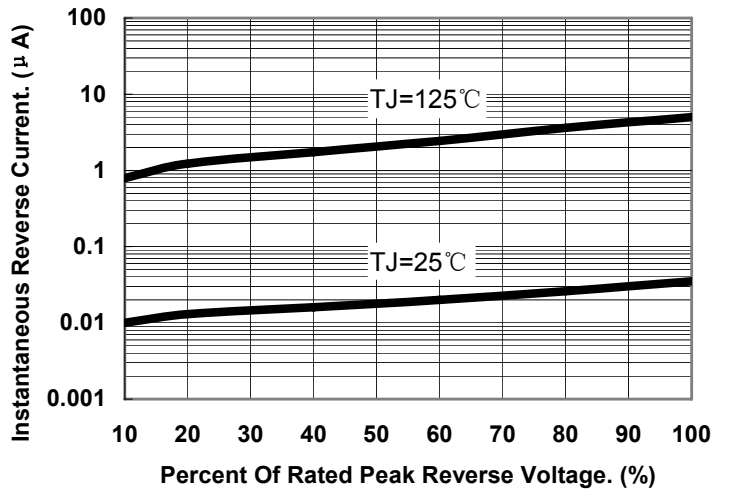


Fig.2-Typical Reverse Characteristics

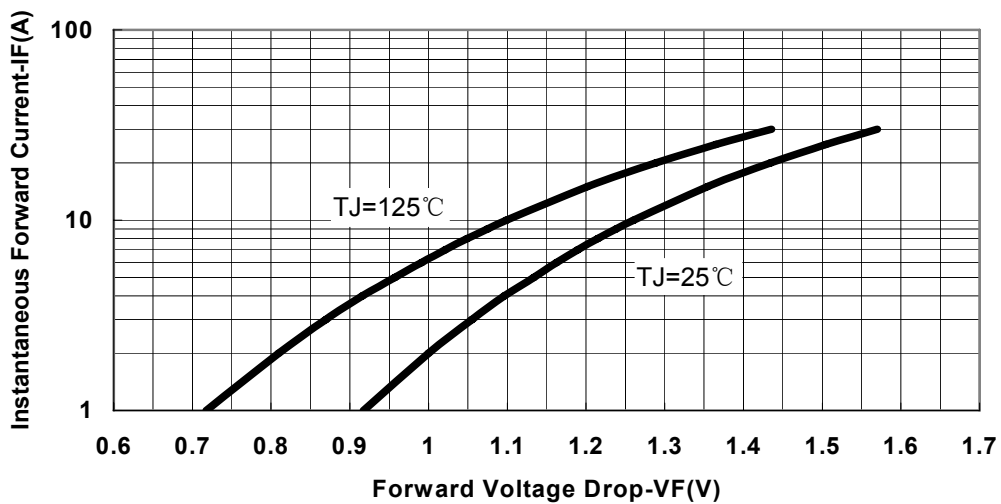


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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